TOSHIBA BIPOLAR DIGITAL INTEGRATED CIRCUIT SILICON MONOLITHIC

TD62502FN,TD62503FN,TD62504FN

7CH SINGLE DRIVER: COMMON EMITTER

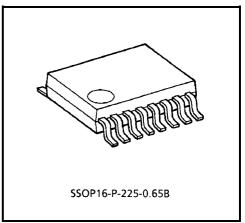
TD62502, 503, 504FN : COMMON EMITTER

The TD62502FN, TD62503FN and TD62504FN are comprised of seven or five NPN Transistor Arrays. Applications include relay, hammer, Lamp and display (LED) drivers.

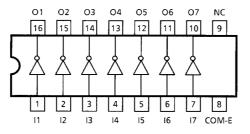
FEATURES

- Output Current (Single Output) 200mA MAX.
- High Sustaining Voltage Output 35V MIN. •
- Inputs Compatible with Various Types of Logic.
- TD62502FN $: R_{IN} = 10.5 \text{ k}\Omega + 7\text{V}$
- Zener Diode…14~25 V P-MOS
- TD62503FN : $R_{IN} = 2.7 \text{ k}\Omega$...TTL, 5 V C-MOS .
- TD62504FN : $R_{IN} = 10.5 \text{ k}\Omega \cdots 6 \sim 15 \text{ V} \text{ P-MOS}$, C-MOS
- : SSOP-16 pin (0.65 mm pitch) Package Type

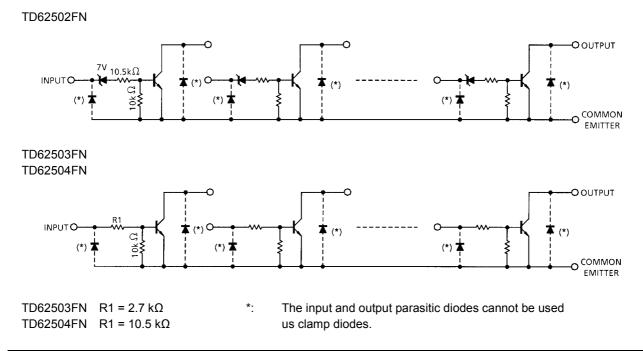
PIN CONNECTION (Top view)



Weight: 0.07 g (Typ.)



SCHEMATICS (Each driver)



MAXIMUM RATINGS (Ta = 25°C Unless otherwise noted)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector-Emitter Voltage	V _{CEO}	35	V
Collector-Base Voltage	V _{CBO}	50	V
Collector Current	Ι _C	200	mA / ch
Input Voltage	V _{IN}	-0.5~30	V
Power Dissipation	P _D (Note 1)	0.78	W
Operating Temperature	T _{opr}	-40~85	°C
Storage Temperature	T _{stg}	-55~150	°C

Note 1: On Glass Epoxy PCB (50 × 50 × 1.6 mm, Cu 40%)

RECOMMENDED OPERATING CONDITIONS (Ta = -40~85°C)

CHARACTERISTIC	SYMBOL	CONDITION	MIN	TYP.	MAX	UNIT
Collector-Emitter Voltage	V _{CEO}		0	_	35	V
Collector-Base Voltage	V _{CBO}		0	_	50	V
Collector Current	Ι _C		0	_	150	mA / ch
Input Voltage	V _{IN}		0	_	25	V
Power Dissipation	P _D (Note 1)	On PCB		_	0.325	W

Note 1: On Glass Epoxy PCB (50 × 50 × 1.6 mm, Cu 40%)

ELECTRICAL CHARACTERISTICS (Ta = 25°C Unless otherwise noted)

CHARA	CTERISTIC	SYMBOL	TEST CIR- CUIT	TEST CONDITION	MIN	TYP.	MAX	UNIT
Output Leakage	Current	ICEX	1	V _{CE} = 35V, V _{IN} = 0 V	-	-	10	μA
Collector-Emitter Saturation Voltage		V _{CE (sat)}	2	I _{IN} = 1 mA, I _C = 10 mA	_	_	0.2	v
				I _{IN} = 3 mA, I _C = 150 mA (Note 1)			0.8	
DC Current Tran	sfer Ration	h _{FE}	2	V _{CE} = 10 V, I _C = 10 mA	50	_	_	
Input Voltage	TD62502FN	V _{IN (ON)} 3	3	I _{IN} = 1 mA, I _C = 10 mA	13	17	23	
	TD62503FN				2.4	3.4	4.2	V
	TD62504FN				7.5	11.5	15	
Turn−On Delay		t _{ON}	4	V _{OUT} = 35 V, R _L = 220Ω	_	50	_	ns
Turn-Off Delay			_	200	—	115		

Note 1: Except TD62502FN

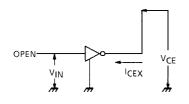
TOSHIBA

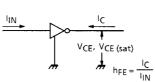
TEST CIRCUIT

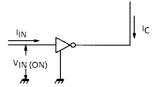
1. ICEX

2. hFE, VCE (sat)

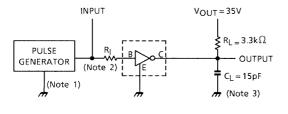
3. VIN (ON)

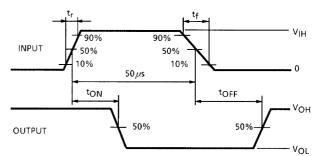






4. t_{ON}, t_{OFF}





Note 1: Pulse Width 50 μ s, Duty Cycle 10% Output Impedance 50 Ω , t_f ≤ 5 ns, t_f ≤ 10 ns Note 2: See below

INPUT CONDITION

TYPE NUMBER	RĮ	VIH
TD62502FN	0 Ω	15 V
TD62503FN	0 Ω	3 V
TD62504FN	0 Ω	10 V

Note 3: CL includes probe and jig capacitance

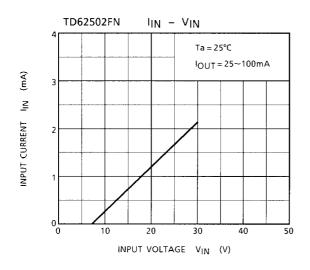
PRECAUTIONS for USING

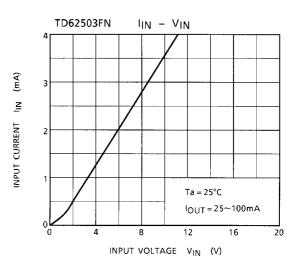
This IC does not integrate protection circuits such as overcurrent and overvoltage protectors.

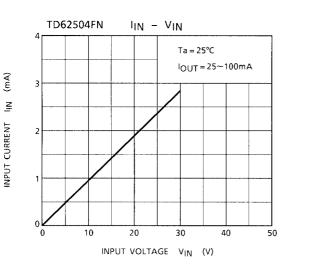
Thus, if excess current or voltage is applied to the IC, the IC may be damaged. Please design the IC so that excess current or voltage will not be applied to the IC.

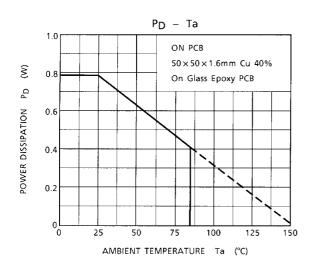
Utmost care is necessary in the design of the output line, V_{CC} and GND line since IC may be destroyed due to short-circuit between outputs, air contamination fault, or fault by improper grounding.

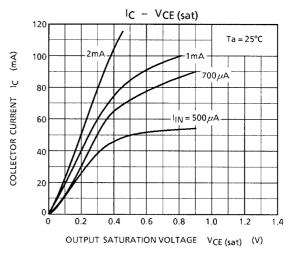
TOSHIBA









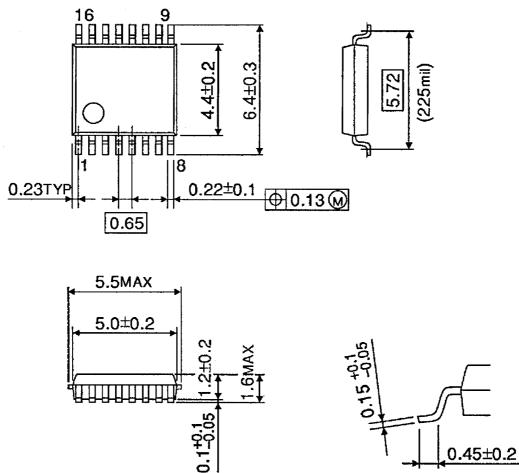




PACKAGE DIMENSIONS

SSOP16-P-225-0.65B

Unit: mm



Weight: 0.07 g (Typ.)

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